NSN 5962-01-370-6639

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-370-6639

Body Length:
1.490 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
0.217 inches
Maximum Power Dissipation Rating:
0.75 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and bidirectional and w/disable and w/enable and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
21 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
120.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Nonvolatile static ram
Voltage Rating And Type Per Characteristic:
-1.0 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
6.00 input pascal industrial light tank stock and 10.00 output pascal industrial light tank stock
Time Rating Per Chacteristic:
300.00 nanoseconds access
Memory Device Type:
Ram
Special Features:
Hardness critical item

NSN 5962-01-370-6639

Memory Microcircuit - Page 2 of 2



Nuclear Hardness Critical Feature	Nuclear	Hardness	Critical	Feature:
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Hardened

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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